Ordering number: EN3825

N-Channel Silicon MOSFET





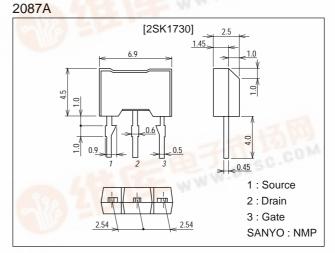
Ultrahigh-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Meets radial taping.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter Symbol Conditions Ratings Drain-to-Source Voltage VDSS 30 Gate-to-Source Voltage VGSS ±15 Drain Current (DC) ID 1.8 Drain Current (Pulse) IDP 7.2 Allowable Power Dissipation PD 1 Channel Temperature Tch 150 Storage Temperature Tstg -55 to +150						
Gate-to-Source Voltage VGSS ±15 Drain Current (DC) ID 1.8 Drain Current (Pulse) IDP 7.2 Allowable Power Dissipation PD 1 Channel Temperature Tch 150	Parameter	Symbol	Conditions	Ratings	Unit	
Drain Current (DC) ID 1.8 Drain Current (Pulse) IDP 7.2 Allowable Power Dissipation PD 1 Channel Temperature Tch 150	Drain-to-Source Voltage	V _{DSS}		30	V	
Drain Current (Pulse) IDP 7.2 Allowable Power Dissipation PD 1 Channel Temperature Tch 150	Gate-to-Source Voltage	V _{GSS}		±15	V	
Allowable Power Dissipation PD 1 Channel Temperature Tch 150	Drain Current (DC)	ID	140	1.8	Α	
Channel Temperature Tch 150	Drain Current (Pulse)	I _{DP}	and Ci	7.2	А	
	Allowable Power Dissipation	PD	a sub-	Livil 07-1	W	
Storage Temperature Tstg -55 to +150	Channel Temperature	Tch	AND ASSET VALUE OF	150	°C	
	Storage Temperature	Tstg		-55 to +150	°C	

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0			100	μA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±12V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.0		2.0	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1A	1.2	2.0	-6.1	S
Static Drain-to-Source ON-State Resistance	R _{DS(on)}	I _D =1A, V _{GS} =10V	1	0.2	0.30	Ω
	R _{DS(on)}	I _D =1A, V _{GS} =4V	AL AL	0.3	0.45	Ω

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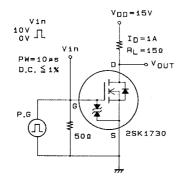
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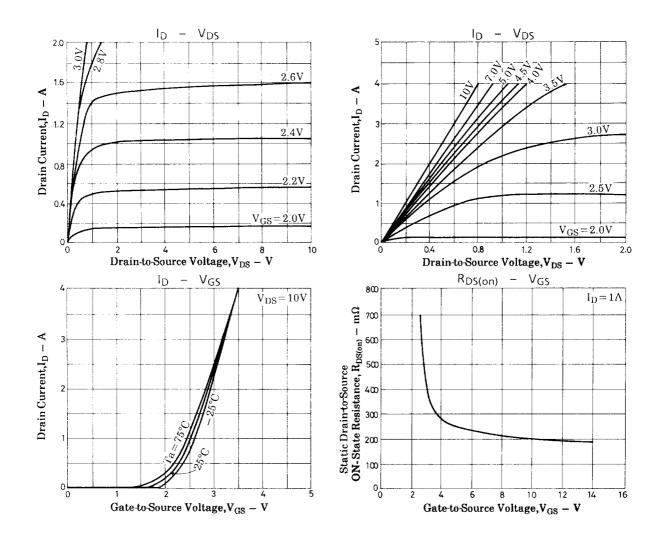
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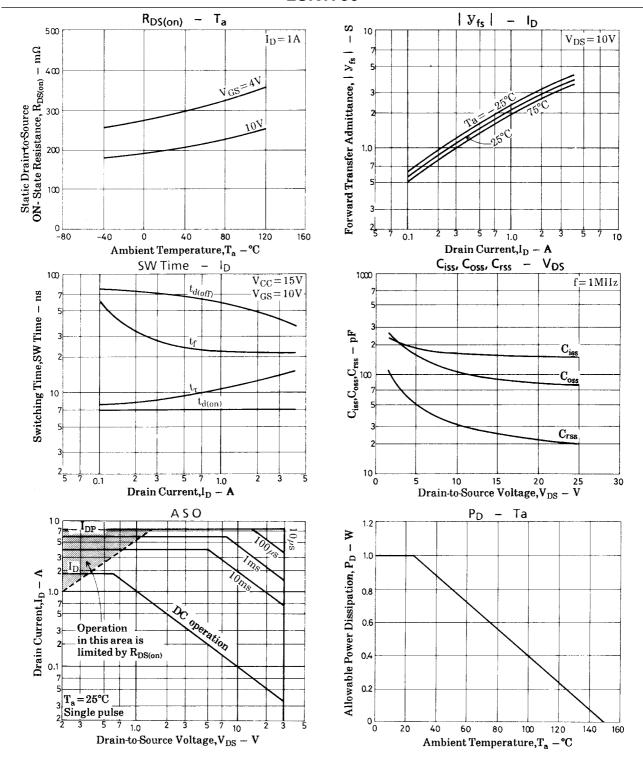
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Parameter	Symbol	Conditions	Ratings	Unit
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz	170	pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz	100	pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz	30	pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit	7	ns
Rise Time	t _r	See specified Test Circuit	11	ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit	60	ns
Fall Time	t _f	See specified Test Circuit	25	ns
Diode Forward Voltage	V _{SD}	I _S =1.8A, V _{GS} =0	0.9	V

Switching Time Test Circuit







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